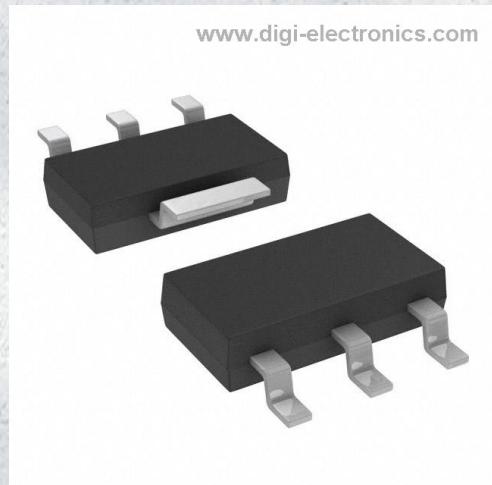


BTS4140NNT Datasheet



DiGi Electronics Part Number	BTS4140NNT-DG
Manufacturer	Infineon Technologies
Manufacturer Product Number	BTS4140NNT
Description	IC PWR SWITCH N-CHAN 1:1 SOT223
Detailed Description	Power Switch/Driver 1:1 N-Channel 200mA PG-SOT 223-4

<https://www.DiGi-Electronics.com>



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BTS4140NNT	Infineon Technologies
Series:	Product Status:
-	Obsolete
Switch Type:	Number of Outputs:
General Purpose	1
Ratio - Input:Output:	Output Configuration:
1:1	High Side
Output Type:	Interface:
N-Channel	On/Off
Voltage - Load:	Voltage - Supply (Vcc/Vdd):
4.9V ~ 60V	Not Required
Current - Output (Max):	Rds On (Typ):
200mA	10hm
Input Type:	Features:
Non-Inverting	Auto Restart
Fault Protection:	Operating Temperature:
Current Limiting (Fixed), Over Temperature, Over Voltage	-40°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Surface Mount	PG-SOT223-4
Package / Case:	Base Product Number:
TO-261-4, TO-261AA	BTS4140

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
3 (168 Hours)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8542.39.0001



Smart High-Side Power Switch

One Channel: 1 x 1Ω

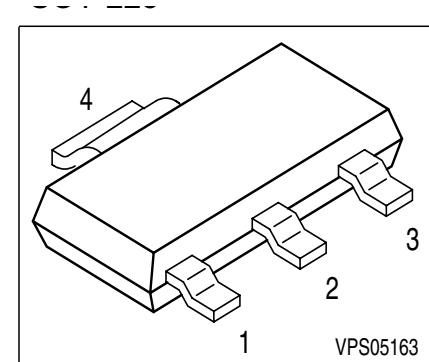


Features

- Current controlled input
- Short circuit protection
- Current limitation
- Overload protection
- Overvoltage protection (including load dump)
- Switching inductive loads
- Clamp of negative voltage at output with inductive loads
- Thermal shutdown with restart
- ESD - Protection
- Loss of GND and loss of V_{bb} protection
- Very low standby current
- Reverse battery protection
- Improved electromagnetic compatibility (EMC)
 - AEC qualified
 - Green product (RoHS compliant)

Product Summary

Overvoltage protection	$V_{bb\text{in(AZ)}}$	62	V
Operating voltage	$V_{bb\text{(on)}}$	4.9...60	V
On-state resistance	R_{ON}	1	Ω



PG-SOT-223

Application

- All types of resistive, inductive and capacitive loads
- Current controlled power switch for 12V, 24V and 42V DC applications
- Driver for electromechanical relays
- Signal amplifier

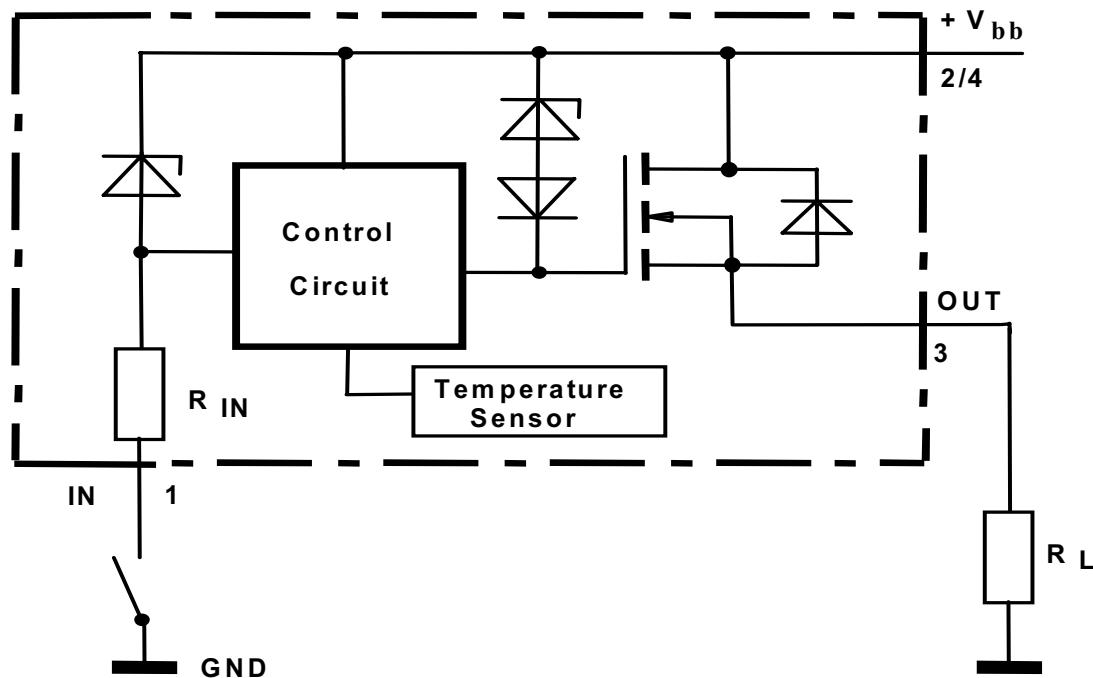
General Description

N channel vertical power MOSFET with charge pump and current controlled input, monolithically integrated in Smart SIPMOS® technology. Providing embedded protective functions.



Smart High-Side Power Switch BTS4140N

Block Diagram



Pin	Symbol	Function
1	IN	Input, activates the power switch in case of connection to GND
2	V _{bb}	Positive power supply voltage
3	OUT	Output to the load
4	V _{bb}	Positive power supply voltage


**Smart High-Side Power Switch
BTS4140N**
Maximum Ratings

Parameter	Symbol	Value	Unit
at $T_j = 25^\circ\text{C}$, unless otherwise specified			
Supply voltage	V_{bb}	60	V
Load current (Short - circuit current, see page 5)	I_L	self limited	A
Maximum current through the input pin (DC)	I_{IN}	± 15	mA
Operating temperature	T_j	-40 ... +150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ... +150	
Power dissipation ¹⁾ $T_A = 25^\circ\text{C}$	P_{tot}	1.7	W
Inductive load switch-off energy dissipation ²⁾ single pulse $T_j = 150^\circ\text{C}$, $I_L = 0.15 \text{ A}$	E_{AS}	1	J
Load dump protection ³⁾ $V_{LoadDump}^{4)} = V_A + V_S$ $R_l=2\Omega$, $t_d=400\text{ms}$, V_{IN} = low or high $I_L = 150 \text{ mA}$, $V_{bb} = 13.5 \text{ V}$ $V_{bb} = 27 \text{ V}$	$V_{LoadDump}$	93.5 127	V
Electrostatic discharge voltage (Human Body Model) according to ANSI EOS/ESD - S5.1 - 1993 ESD STM5.1 - 1998 Input pin all other pins	V_{ESD}	± 1 ± 5	kV

¹Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70µm thick) copper area for V_{bb} connection. PCB is vertical without blown air.

²not subject to production test, specified by design

³more details see EMC-Characteristics on page 7

⁴ $V_{LoadDump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839 .



Smart High-Side Power Switch BTS4140N

Electrical Characteristics

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
at $T_j = -40\ldots150^\circ\text{C}$, $V_{bb} = 9\ldots42\text{ V}$ unless otherwise specified					

Thermal Characteristics

Thermal resistance @ min. footprint	$R_{th(JA)}$	-	86	125	K/W
Thermal resistance @ 6 cm ² cooling area ¹⁾	$R_{th(JA)}$	-	60	72	
Thermal resistance, junction - soldering point	R_{thJS}	-	-	17	

Load Switching Capabilities and Characteristics

On-state resistance Pin1 connected to GND $T_j = 25^\circ\text{C}$, $I_L = 150\text{ mA}$, $V_{bb} = 9\ldots52\text{ V}$ $T_j = 150^\circ\text{C}$ $T_j = 25^\circ\text{C}$, $I_L = 50\text{ mA}$, $V_{bb} = 6\text{ V}$	R_{ON}				Ω
Nominal load current ²⁾ Device on PCB ¹⁾ $T_a = 85^\circ\text{C}$, $T_j \leq 150^\circ\text{C}$	$I_{L(nom)}$	0.2	-	-	A
Turn-on time ³⁾ $V_{IN} = V_{bb}$ to 0V to 90% V_{OUT} $R_L = 270\ \Omega$ $R_L = 270\ \Omega$, $V_{bb} = 13.5\text{ V}$, $T_j = 25^\circ\text{C}$	t_{on}	-	1	1.5	μs
		-	1.5	3	
		-	2	5	
Turn-off time ³⁾ $V_{IN} = 0\text{V}$ to V_{bb} to 10% V_{OUT} $R_L = 270\ \Omega$ $R_L = 270\ \Omega$, $V_{bb} = 13.5\text{ V}$, $T_j = 25^\circ\text{C}$	t_{off}	-	-	125 ⁴⁾	μs
		-	45	100	
Slew rate on ³⁾ $V_{IN} = V_{bb}$ to 0V 10 to 30% V_{OUT} $R_L = 270\ \Omega$ $R_L = 270\ \Omega$, $T_j = 25^\circ\text{C}$, $V_{bb} = 13.5\text{ V}$	dV/dt_{on}	-	-	175 ⁴⁾	$\text{V}/\mu\text{s}$
		-	1.3	4	
Slew rate off ³⁾ $V_{IN} = 0\text{V}$ to V_{bb} 70 to 40% V_{OUT} $R_L = 270\ \Omega$ $R_L = 270\ \Omega$, $T_j = 25^\circ\text{C}$, $V_{bb} = 13.5\text{ V}$	$-dV/dt_{off}$	-	-	6 ⁴⁾	
		-	1.7	4	

¹Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70μm thick) copper area for V_{bb} connection. PCB is vertical without blown air.

²Nominal load current is limited by the current limitation (see page 5)

³Timing values only with high input slewrates, otherwise slower.

⁴not subject to production test, specified by design


**Smart High-Side Power Switch
BTS4140N**
Electrical Characteristics

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
at $T_j = -40 \dots 150^\circ\text{C}$, $V_{bb} = 9 \dots 42 \text{ V}$ unless otherwise specified					

Operating Parameters

Operating voltage	$V_{bb(on)}$	4.9	-	60	V
Standby current Pin1 = open	$I_{bb(off)}$	-	2	10	μA

Protection Functions¹⁾

Initial peak short circuit current limit (see page 11) $T_j = -40^\circ\text{C}$, $V_{bb} = 13.5 \text{ V}$, $t_m = 100 \mu\text{s}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_{L(SCP)}$				A
		-	-	1.2	
		-	0.9	-	
		0.2	-	-	
Repetitive short circuit current limit $T_j = T_{jt}$	$I_{L(SCR)}$	-	0.7	-	
Output clamp (inductive load switch off) at $V_{OUT} = V_{bb} - V_{ON(CL)}$, $I_{bb} = 4 \text{ mA}$	$V_{ON(CL)}$	60	-	-	V
Overvoltage protection $I_{bb} = 1 \text{ mA}$	$V_{bbin(AZ)}$	62	68	-	
Thermal overload trip temperature	T_{jt}	150	-	-	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	-	10	-	K

¹⁾ Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.


**Smart High-Side Power Switch
BTS4140N**
Electrical Characteristics

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
at $T_j = -40\ldots150^\circ\text{C}$, $V_{bb} = 9\ldots42\text{ V}$ unless otherwise specified					
Input					
Off state input current $V_{OUT} \leq 0.1\text{ V}$	$I_{IN(off)}$	-	-	0.05	mA
$T_j = 25^\circ\text{C}$, $R_L = 270\text{ }\Omega$		-	-	0.04	
$T_j = 150^\circ\text{C}$					
On state input current (Pin1 grounded) ¹⁾	$I_{IN(on)}$	-	0.3	1	
Input resistance	R_I	0.5	1	2.5	k Ω

Reverse Battery

Continuous reverse drain current $T_C = 25^\circ\text{C}$	I_S	-	-	0.2	A
Drain-source diode voltage ($V_{OUT} > V_{bb}$) $I_F = 0.2\text{ A}$, $I_{IN} \leq 0.05\text{ mA}$	$-V_{ON}$	-	600	-	mV

¹⁾Driver circuit must be able to drive currents > 1mA.



Smart High-Side Power Switch BTS4140N

EMC-Characteristics

All EMC-Characteristics are based on limited number of samples and no part of production test.

Test Conditions:

If not otherwise specified the test circuitry is the minimal functional configuration without any external components for protection or filtering.

Supply voltage: $V_{bb} = 13.5V$ Temperature: $T_a = 23 \pm 5^\circ C$;

Load: $R_L = 220\Omega$

Operation mode: PWM Frequency: 100Hz / Duty Cycle: 50%
DC On/Off

DUT-Specific.: -

Fast electrical transients

Acc. ISO 7637

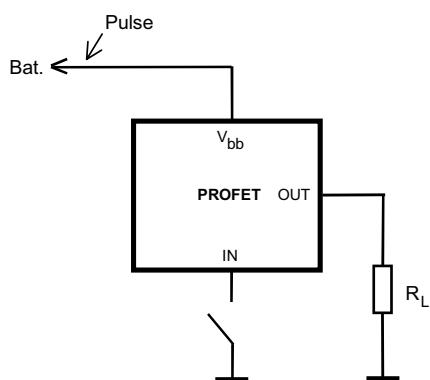
Test Pulse	Test Level	Test Results		Pulse Cycle Time and Generator Impedance
		On	Off	
1	-200 V	C	C	500ms ; 10Ω
2	+200 V	C	C	500ms ; 10Ω
3a	-200 V	C	C	100ms ; 50Ω
3b	+200 V	C	C	100ms ; 50Ω
41)	-7 V	C	C	0,01Ω
5	175 V	E (150V)	E (150V)	400ms ; 2Ω

The test pulses are applied at V_{bb}

Definition of functional status

Class	Content
C	All functions of the device are performed as designed after exposure to disturbance.
E	One or more function of a device does not perform as designed after exposure and can not be returned to proper operation without repairing or replacing the device. The value after the character shows the limit.

Test circuit:



¹Supply voltage $V_{bb} = 12 V$ instead of 13,5 V.

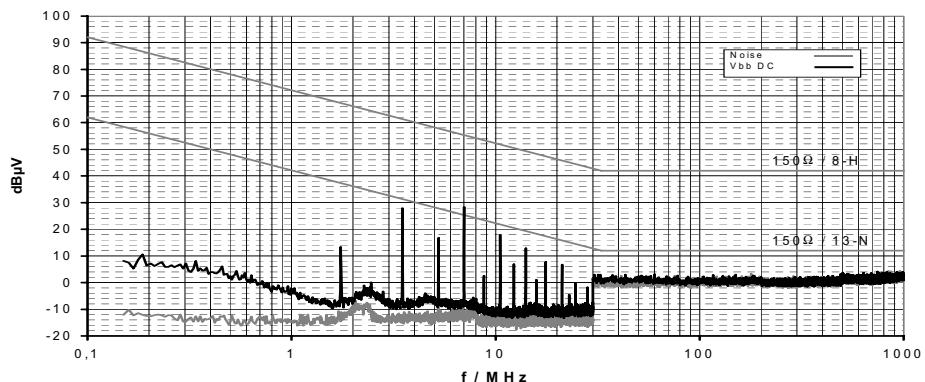


Smart High-Side Power Switch BTS4140N

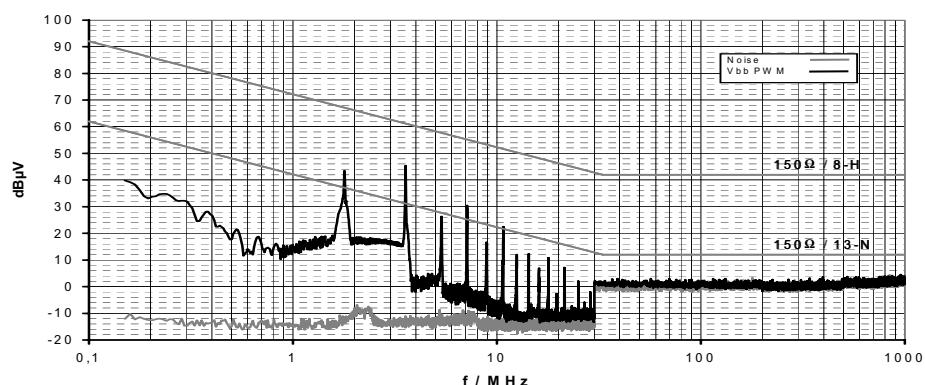
Conducted Emission

Acc. IEC 61967-4 (1Ω / 150Ω method)

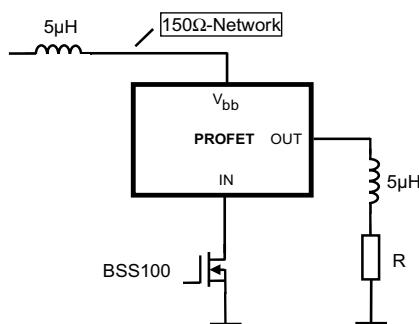
Typ. V_{bb} -Pin Emission at DC-On with 150Ω-matching network



Typ. V_{bb} -Pin Emission at PWM-Mode with 150Ω-matching network



Test circuit:



For defined decoupling and high reproducibility a defined choke (5μH at 1 MHz) is inserted between supply and V_{bb} -pin.



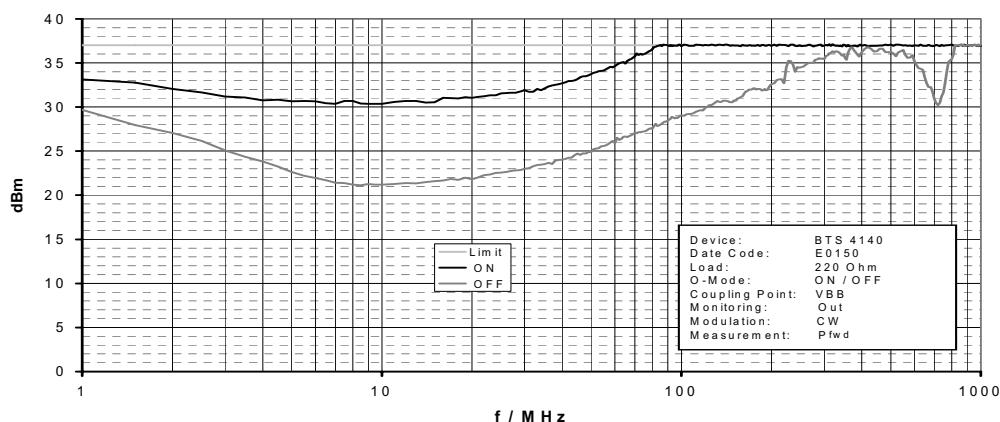
Conducted Susceptibility

Acc. 47A/658/CD IEC 62132-4 (Direct Power Injection)

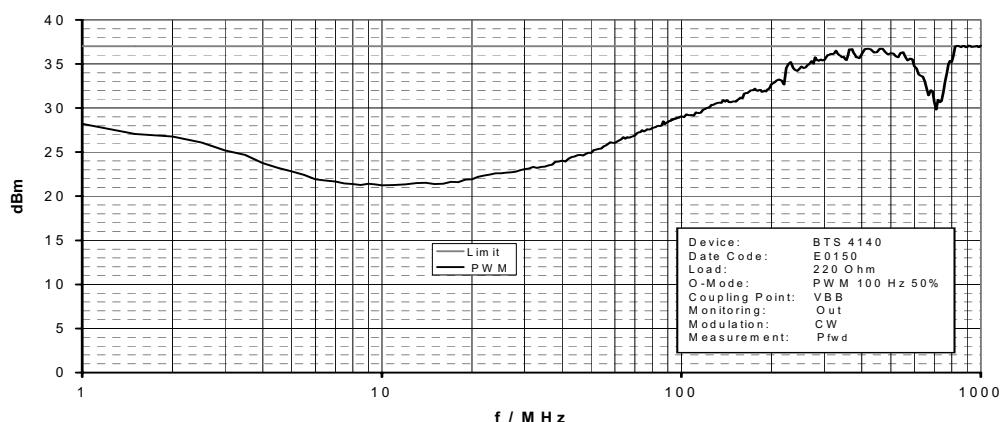
Direct Power Injection: Forward Power CW

Failure criteria: Amplitude and frequency deviation max. 10% at Out

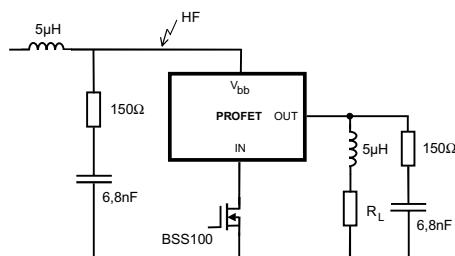
Typ. V_{bb} -Pin Susceptibility at DC-On/Off



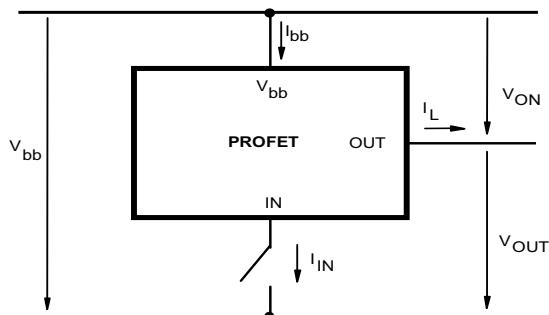
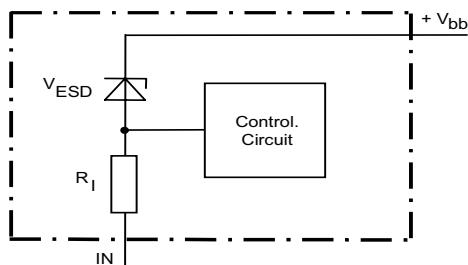
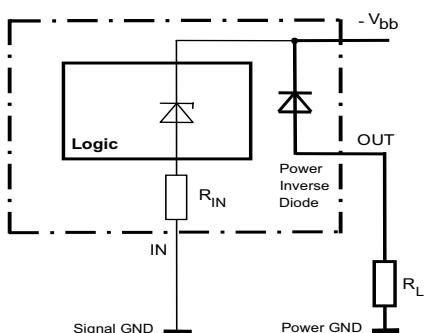
Typ. V_{bb} -Pin Susceptibility at PWM-Mode



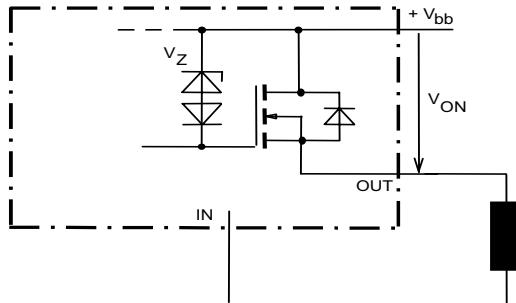
Test circuit:



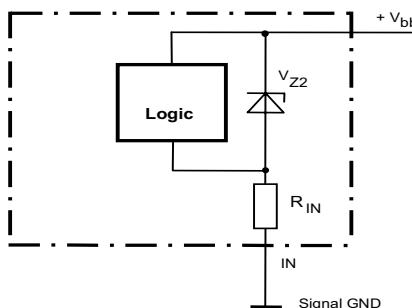
For defined decoupling and high reproducibility the same choke and the same 150Ω -matching network as for the emission measurement is used.

Terms**Input circuit (ESD protection)****Reverse battery protection**

$R_I = 1\text{k}\Omega$ typ., Temperature protection is not active during inverse current.

Inductive and overvoltage output clamp

V_{ON} clamped to 60 V min.

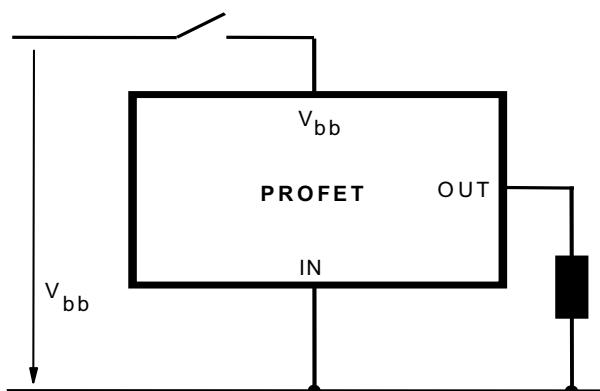
Overvoltage protection of logic part

$V_{bb,AZ} = V_{Z2} + I_{bb} * R_{IN} = 62\text{V}$ min.

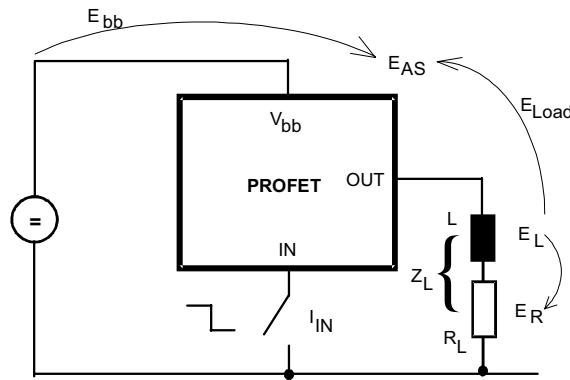


Smart High-Side Power Switch BTS4140N

V_{bb} disconnect with charged inductive load



Inductive Load switch-off energy dissipation



$$\text{Energy stored in load inductance: } E_L = \frac{1}{2} * L * I_L^2$$

While demagnetizing load inductance,
the energy dissipated in PROFET is
 $E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} * i_L(t) dt$,
with an approximate solution for $R_L > 0\Omega$:

$$E_{AS} = \frac{I_L * L}{2 * R_L} * (V_{bb} + |V_{OUT(CL)}|) * \ln\left(1 + \frac{I_L * R_L}{|V_{OUT(CL)}|}\right)$$

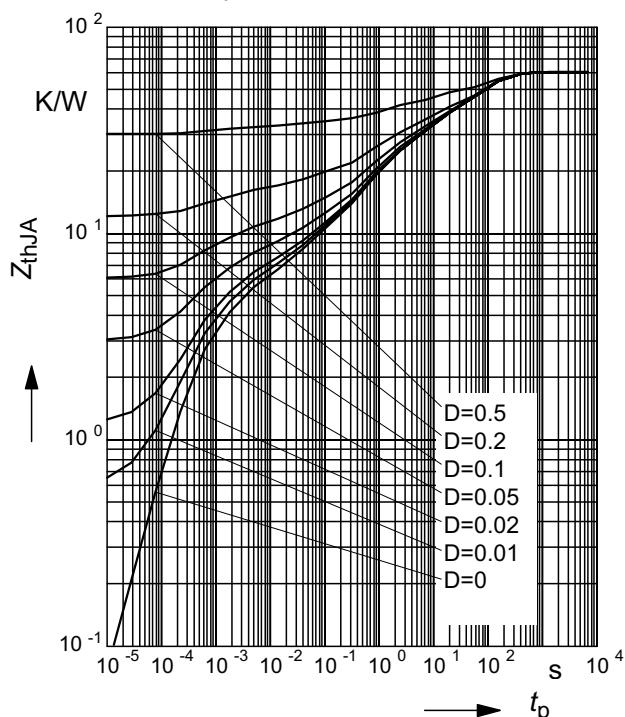


Smart High-Side Power Switch BTS4140N

Typ. transient thermal impedance

$Z_{thJA} = f(t_p)$ @ 6cm² heatsink area

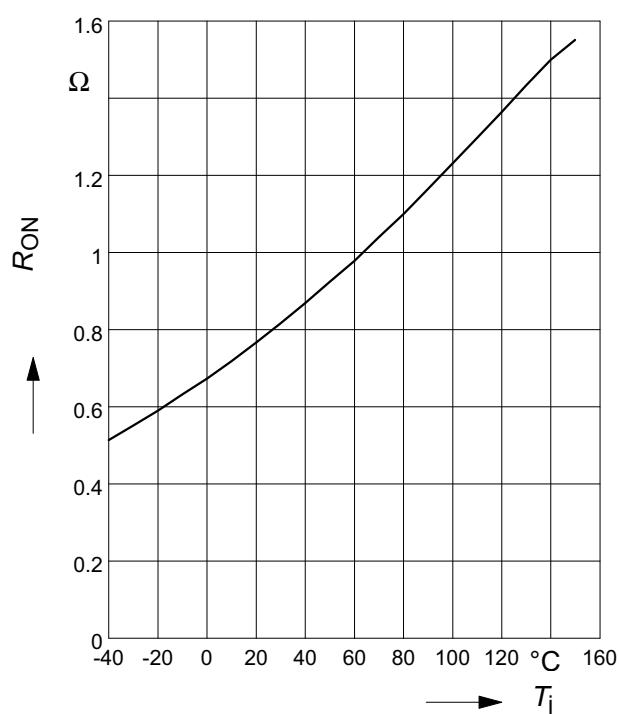
Parameter: $D = t_p/T$



Typ. on-state resistance

$R_{ON} = f(T_j)$; $V_{bb} = 9V$; Pin1 grounded;

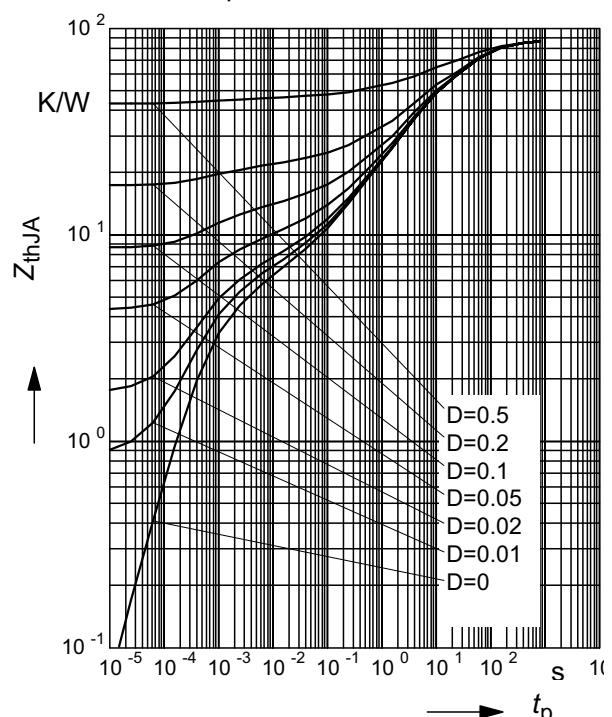
$I_L = 150mA$



Typ. transient thermal impedance

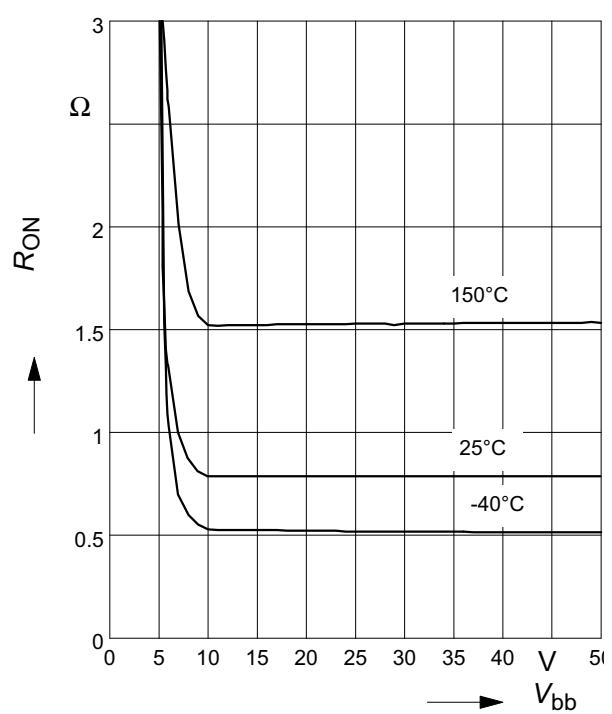
$Z_{thJA} = f(t_p)$ @ min. footprint

Parameter: $D = t_p/T$



Typ. on-state resistance

$R_{ON} = f(V_{bb})$; $I_L = 150mA$; Pin1 grounded

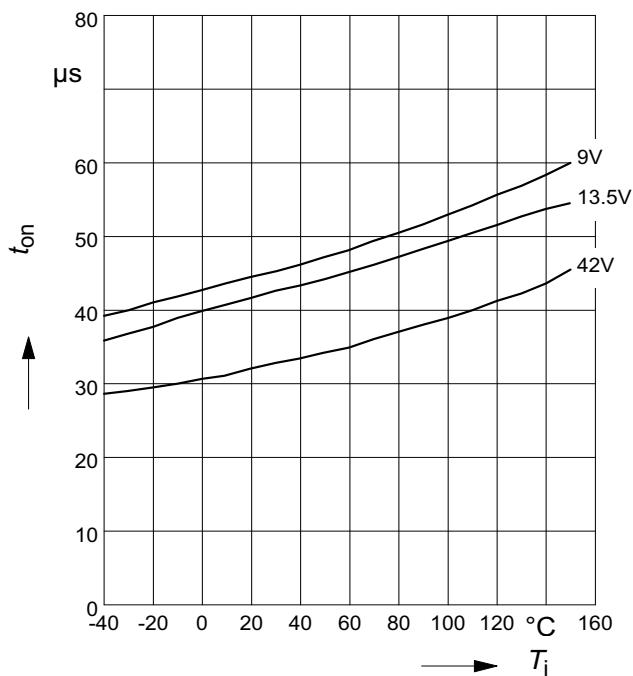




Smart High-Side Power Switch BTS4140N

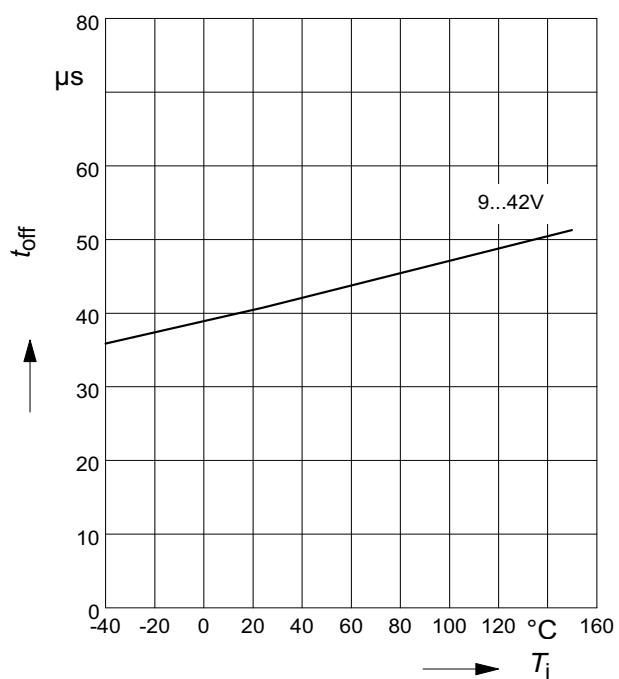
Typ. turn on time

$$t_{\text{on}} = f(T_j); R_L = 270\Omega$$



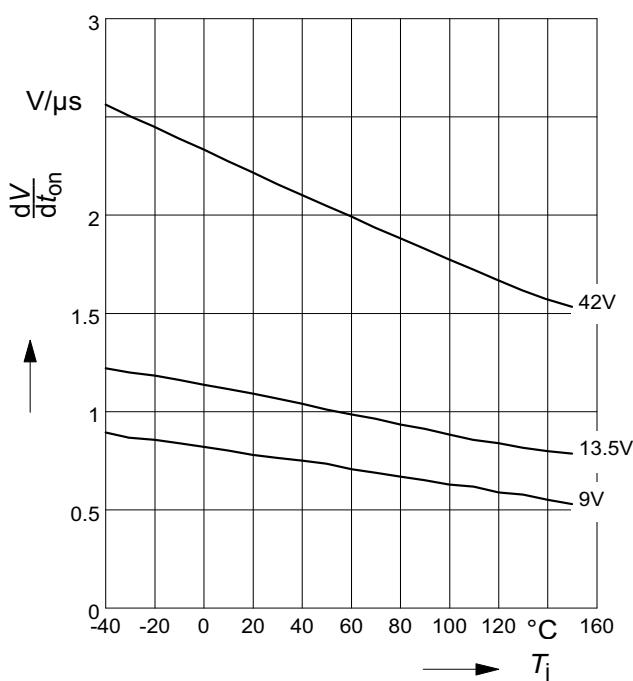
Typ. turn off time

$$t_{\text{off}} = f(T_j); R_L = 270\Omega$$



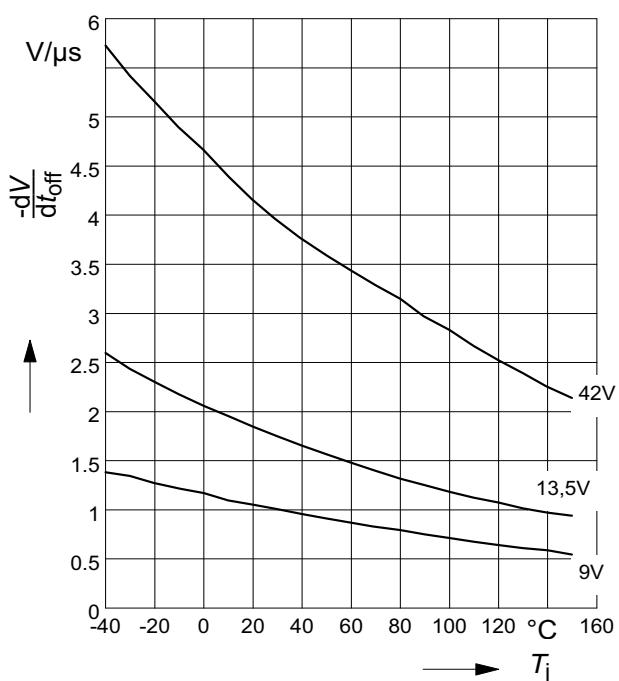
Typ. slew rate on

$$dV/dt_{\text{on}} = f(T_j); R_L = 270 \Omega$$



Typ. slew rate off

$$dV/dt_{\text{off}} = f(T_j); R_L = 270 \Omega$$

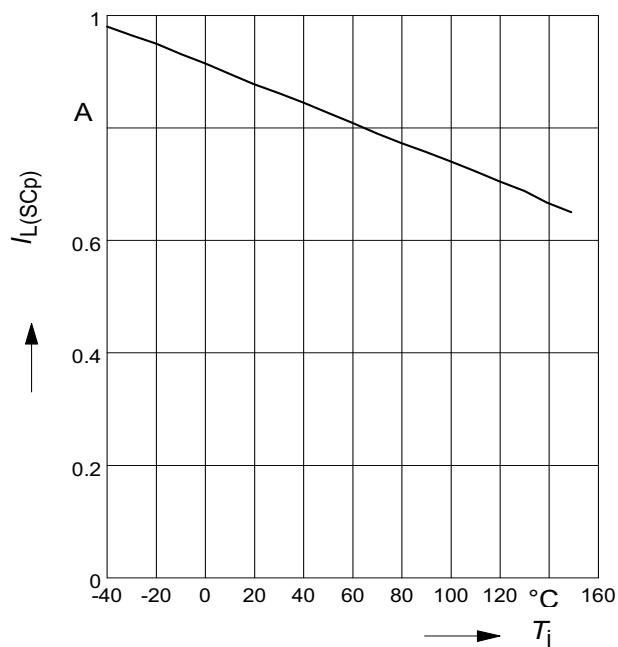




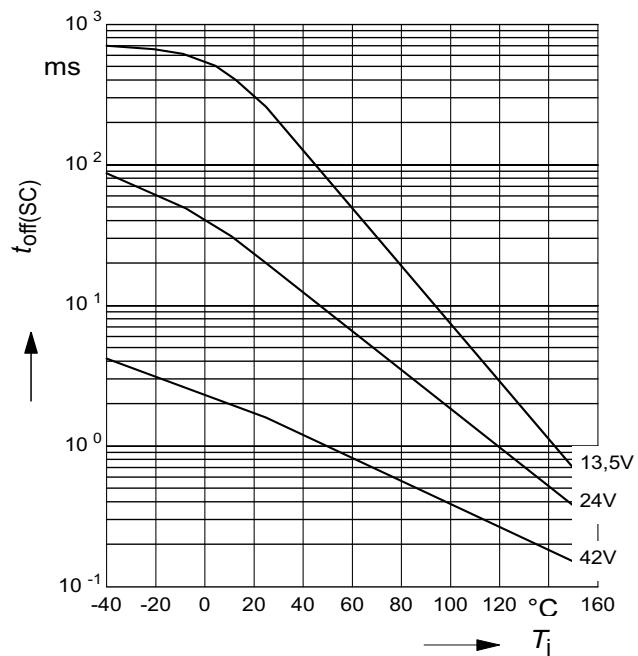
Smart High-Side Power Switch BTS4140N

Typ. initial peak short circuit current limit

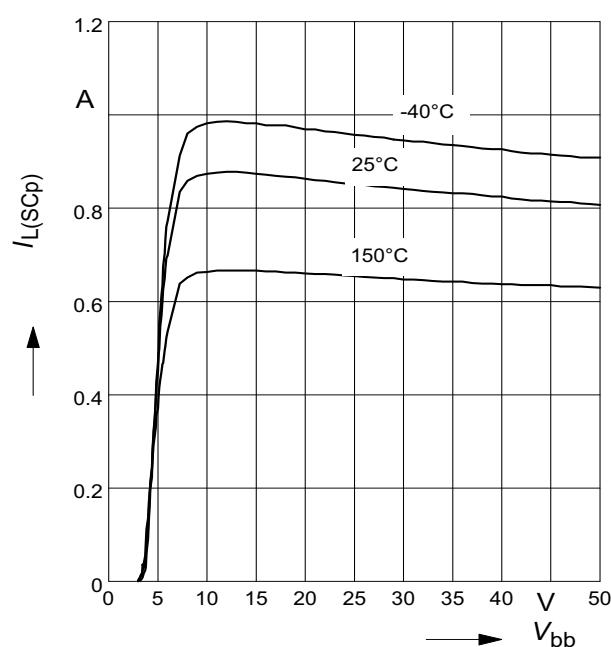
$$I_{L(SCp)} = f(T_j); V_{bb} = 13,5 \text{ V}; t_m = 100 \mu\text{s}$$

**Typ. initial short circuit shutdown time**

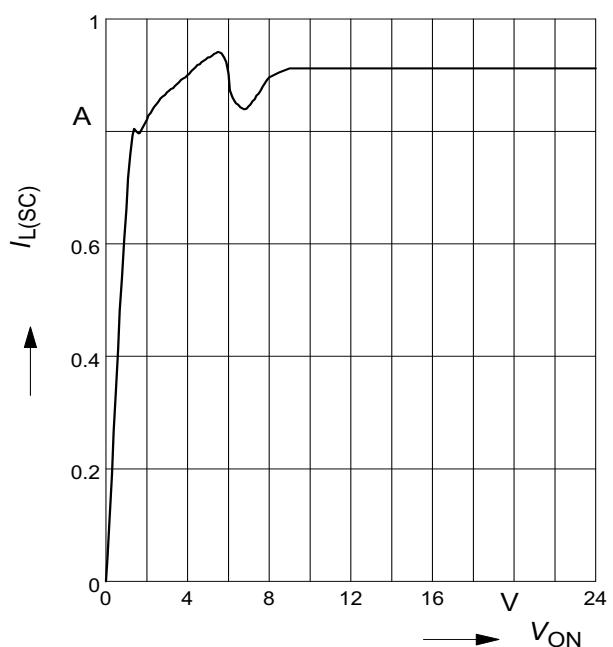
$$t_{off(SC)} = f(T_{j,start})$$

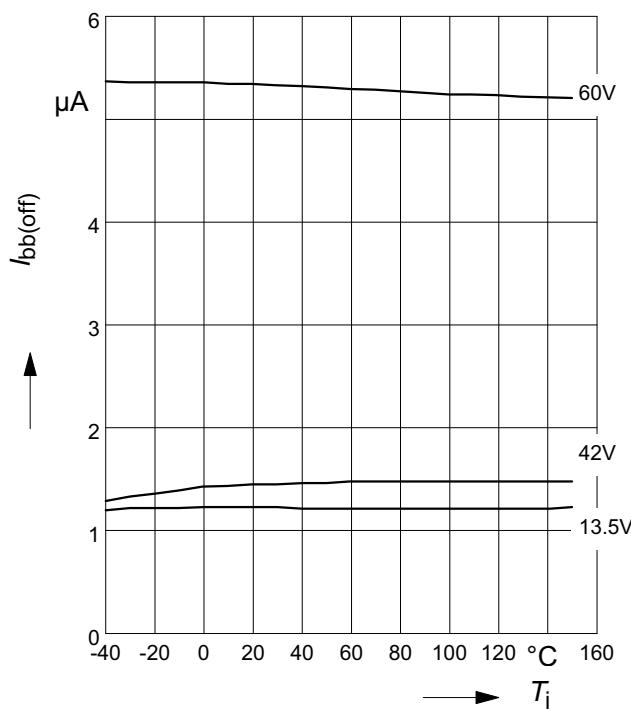
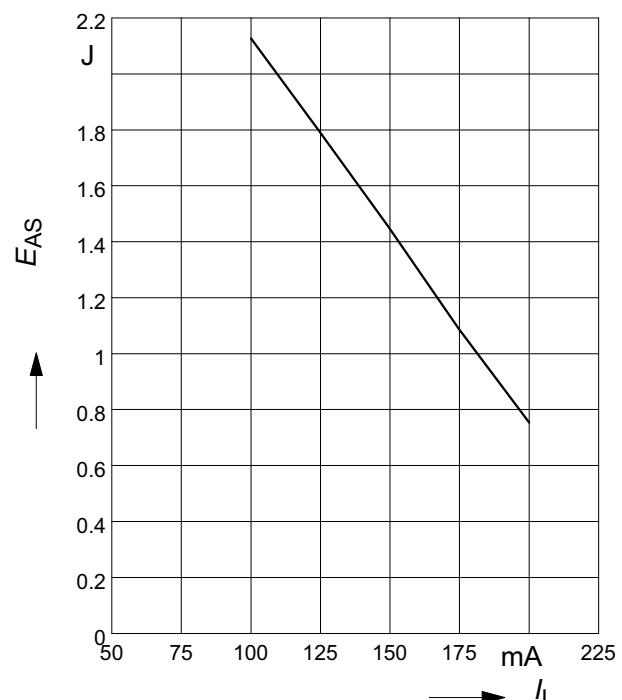
**Typ. initial peak short circuit current limit**

$$I_{L(SCp)} = f(V_{bb}); t_m = 100 \mu\text{s}$$

**Typ. current limitation characteristic:**

$$I_{L(SC)} = f(V_{ON}), V_{bb} = 13,5 \text{ V}$$



Typ. standby current
 $I_{bb(\text{off})} = f(T_j)$; Pin1 open

Maximum allowable inductive switch-off energy, single pulse
 $E_{AS} = f(I_L)$; $T_{j\text{start}} = 150^\circ\text{C}$




Smart High-Side Power Switch BTS4140N

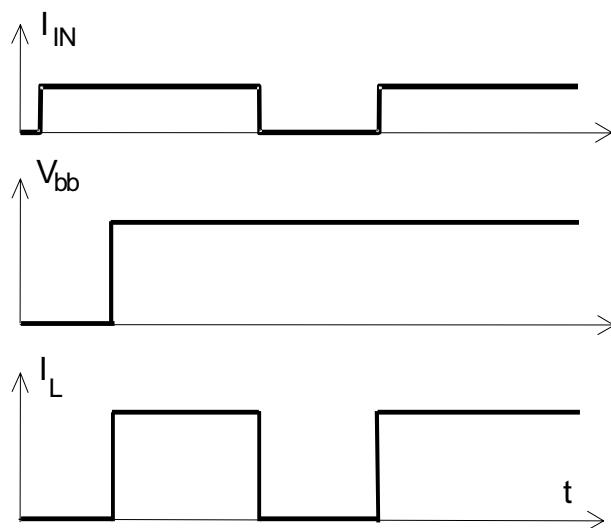
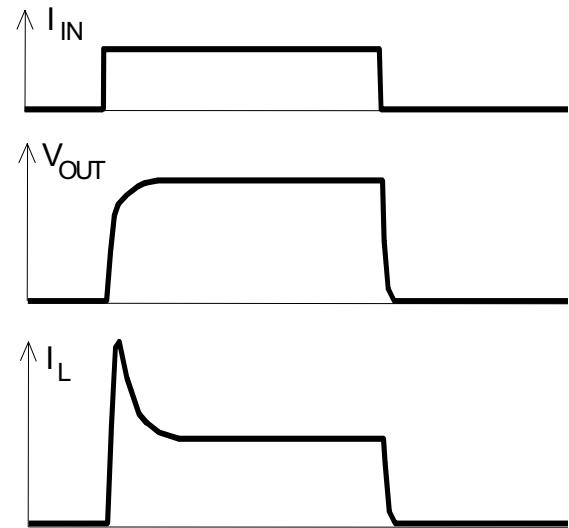
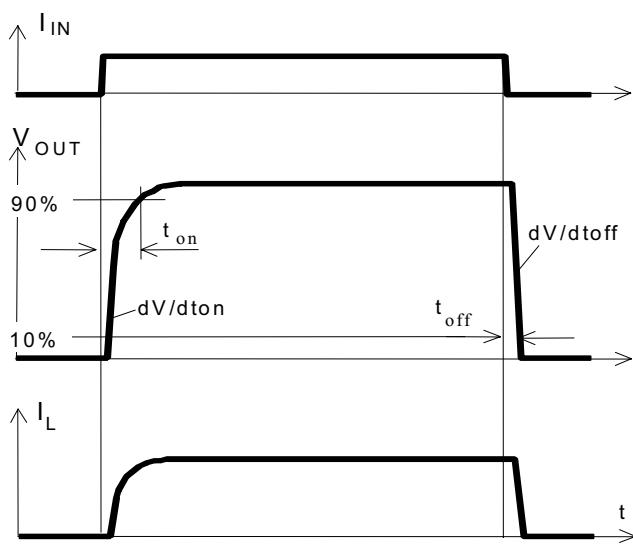
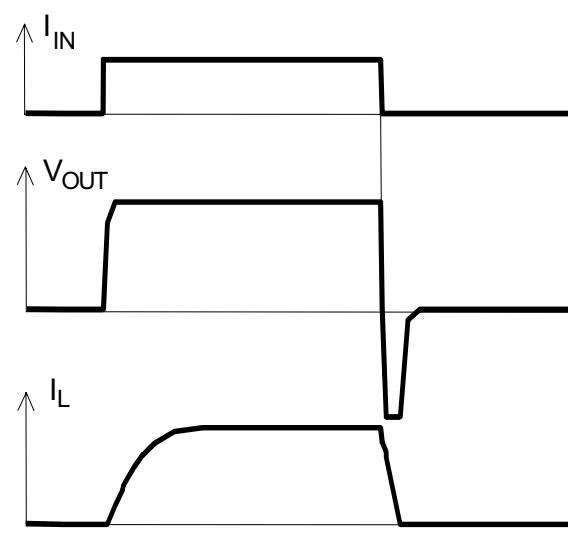
Figure 1a: V_{bb} turn on:**Figure 2b:** Switching a lamp**Figure 2a:** Switching a resistive load,
turn-on/off time and slew rate definition**Figure 2c:** Switching an inductive load

Figure 3a: Turn on into short circuit,
shut down by overtemperature, restart by cooling

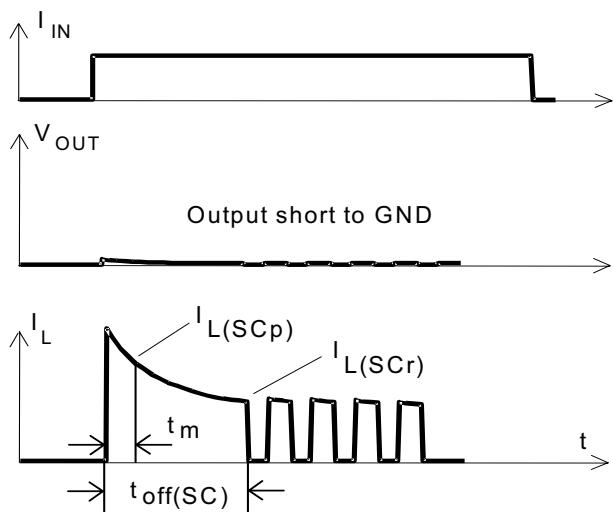
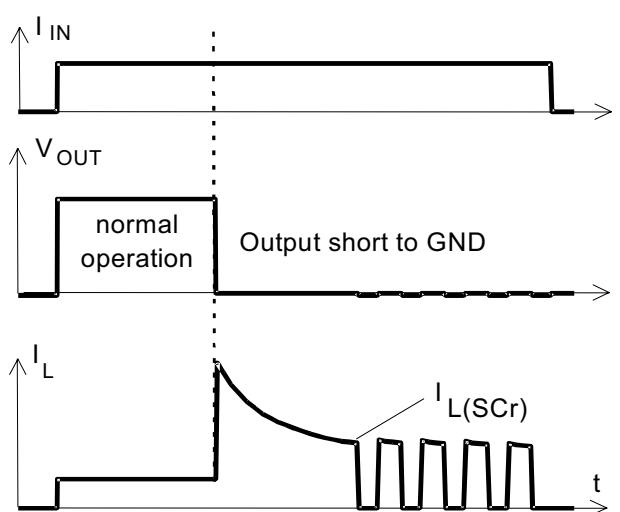
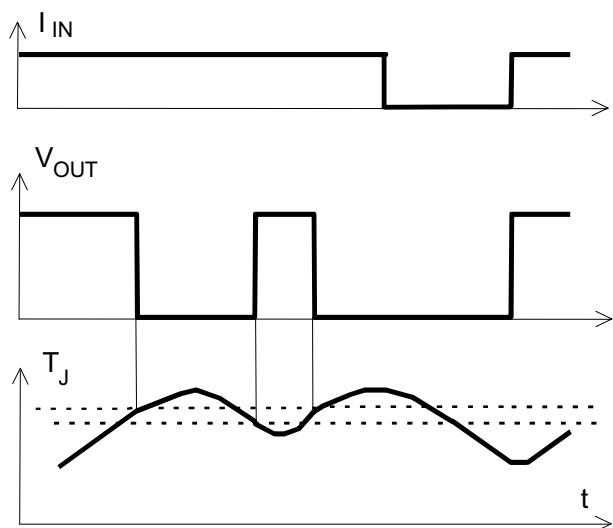


Figure 3b: Short circuit in on-state
shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions.

Figure 4: Overtemperature:
Reset if $T_j < T_{jt}$



Package Outlines

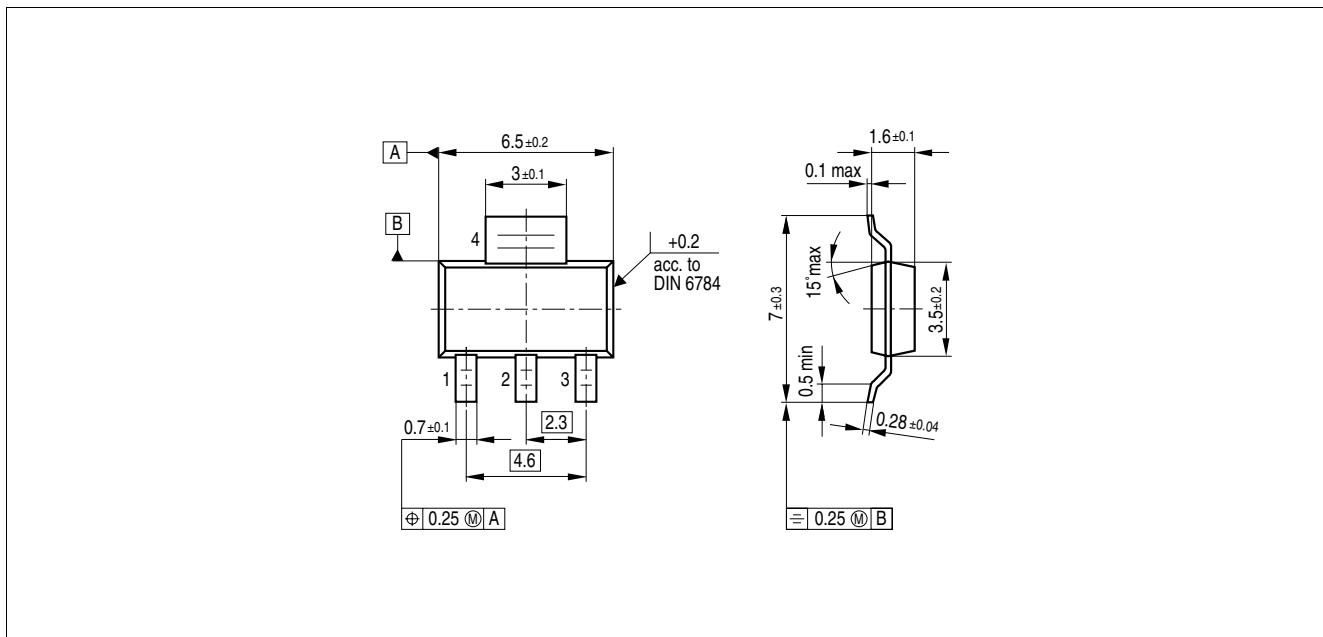


Figure 1 PG-SOT-223 (Plastic Dual Small Outline Package) (RoHS-compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

You can find all of our packages, sorts of packing and others in our
 Infineon Internet Page "Products": <http://www.infineon.com/products>.

Dimensions in mm



Revision History

Version	Date	Changes
V1.1	2007-05-29	<p>Creation of the green datasheet.</p> <p>First page :</p> <p>Adding the green logo and the AEC qualified</p> <p>Adding the bullet AEC qualified and the RoHS compliant features</p> <p>Package page</p> <p>Modification of the package to be green.</p>

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